

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant:	Haupt	Docket No.:	QIM 2003 P 51718 US
Serial No.:	10/766,053	Art Unit:	2892
Filed:	January 28, 2004	Examiner:	Thanh Y. Tran
		Conf. No.:	2311
For:	Method for N+ Doping of Amorphous Silicon and Polysilicon Electrodes in Deep Trenches		

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Dear Sir:

The following amendments and remarks are presented in response to the Examiner's Office Action mailed October 3, 2008. This amendment is accompanied by a Petition for Revival of an Application for Patent Abandoned Unintentionally. Please amend the above-referenced application as follows.